NSN 5962-01-379-5574

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View Online at https://aerobasegroup.com/nsn/5962-01-379-5574

Body Length:	
1.490 inches	
Body Width:	
0.610 inches	
Body Height:	
0.217 inches	
Maximum Power Dissipation Rating:	
1.0 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and burn in and monolithic and ultraviolet erasable and programmed and electrostatic sensitive	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
17 input	
Case Outline Source And Designator:	
D-10 mil-m-38510	
Current Rating Per Characteristic:	
150.00 milliamperes reverse current, dc absolute	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
7.0 volts power source	
Capitance Rating Per Characteristic:	
Between 6.00 input picofarads and 12.00 output picofarads	
Time Rating Per Chacteristic:	
250.00 nanoseconds access	
Memory Device Type:	
Eprom	
Special Features:	
B96906-mil-std-883	
Terminal Type And Quantity:	
28 printed circuit	
Shelf Life:	
N/a	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

